GenX3 ${ }^{\text {TM }} 1400 \mathrm{~V}$ IGBTs IXGH20N140C3H1 w/ Diode

High-Speed PT IGBTs
for 20-50 kHz Switching


TO-247 (IXGH)

| Symbol | Test Conditions | Maximum | tings |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {ces }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 1400 | V |
| $\mathrm{V}_{\text {cGR }}$ | $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{GE}}=1 \mathrm{M} \Omega$ | 1400 | V |
| $V_{\text {GES }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GEM }}$ | Transient | $\pm 30$ | V |
| $\mathrm{I}_{\mathrm{C} 25}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 42 | A |
| $\mathrm{I}_{\mathrm{C} 100}$ | $\mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}$ | 20 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, 1 \mathrm{~ms}$ | 108 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 20 | A |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 400 | mJ |
| SSOA | $\mathrm{V}_{G E}=15 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{G}}=5 \Omega$ | $\mathrm{I}_{\mathrm{CM}}=40$ | A |
| (RBSOA) | Clamped Inductive Load | $\mathrm{V}_{\mathrm{CE}} \leq \mathrm{V}_{\text {CES }}$ |  |
| $\mathrm{P}_{\mathrm{c}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 250 | W |
| $\mathrm{T}_{\mathrm{J}}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{JM}}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062 in.) from Case for 10s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {SoLD }}$ | Plastic Body for 10 seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting Torque (TO-247) | 1.13/10 | Nm/lb.in. |
| Weight | TO-247 | 6 | g |
|  | TO-268 | 4 | g |




TO-268 (IXGT)

$\mathrm{G}=$ Gate $\quad \mathrm{C}=$ Collector
$\mathrm{E}=$ Emitter $\quad$ Tab $=$ Collector

Features

- Optimized for Low Switching Losses
- Square RBSOA
- High Avalanche Capability
- Anti-Parallel Ultra Fast Diode
- International Standard Packages


## Advantages

- High Power Density
- Low Gate Drive Requirement


## Applications

- High Frequency Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

Symbol Test Conditions
( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified)

| $\mathrm{g}_{\mathrm{ts}}$ | $\mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\text {c100 }}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}$, Note 1 | 10 | 17 | S |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \hline \mathrm{C}_{\text {ies }} \\ & \mathrm{C}_{\text {oes }} \\ & \mathrm{C}_{\text {res }} \end{aligned}$ | $\mathrm{V}_{\mathrm{CE}}=25 \mathrm{~V}, \mathrm{~V}_{\mathrm{GE}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | $\begin{array}{r} 1790 \\ 145 \\ 50 \\ \hline \end{array}$ | pF pF pF |
| $\begin{aligned} & \mathbf{Q}_{\mathrm{g}} \\ & \mathbf{Q}_{\mathrm{ge}} \\ & \mathbf{Q}_{\mathrm{gc}} \end{aligned}$ | $\mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\mathrm{C} 100}, \mathrm{~V}_{\text {GE }}=15 \mathrm{~V}, \mathrm{~V}_{\text {CE }}=0.5 \cdot \mathrm{~V}_{\text {CES }}$ |  | 88 18 30 | nC nc C |
|  | Inductive load, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ $\begin{aligned} & \mathrm{I}_{\mathrm{c}}=\mathrm{I}_{\mathrm{C} 100}, \mathrm{~V}_{\mathrm{GE}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=0.5 \cdot \mathrm{~V}_{\mathrm{CEE}}, \mathrm{R}_{\mathrm{G}}=5 \Omega \end{aligned}$ <br> Note 2 |  | $\begin{array}{r} 19 \\ 12 \\ 1.35 \\ 110 \\ 32 \\ 0.44 \end{array}$ | ns mJ ns ns 0.80 mJ |
|  | Inductive load, $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\mathrm{C} 100}, \mathrm{~V}_{\mathrm{GE}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=0.5 \cdot \mathrm{~V}_{\mathrm{CES}}, \mathrm{R}_{\mathrm{G}}=5 \Omega \end{aligned}$ <br> Note 2 |  | $\begin{array}{r} 22 \\ 13 \\ 2.33 \\ 144 \\ 380 \\ 1.64 \end{array}$ | mJ ns ns mJ |
| $\begin{aligned} & \mathbf{R}_{\mathrm{thnc}} \\ & \mathbf{R}_{\mathrm{thnck}} \end{aligned}$ | TO-247 |  | 0.21 | $\begin{array}{r} 0.50^{\circ} \mathrm{C} / \mathrm{W} \\ { }^{\circ} \mathrm{C} / \mathrm{W} \end{array}$ |

## Reverse Diode (FRED)



Notes:

1. Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle, $\mathrm{d} \leq 2 \%$.
2. Switching times \& energy losses may increase for higher $V_{C E}$ (Clamp), $T_{J}$ or $R_{G}$.

## ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

TO-247 Outline


Terminals: 1 - Gate 2 - Collector
3 - Emitter

| Dim. | Millimeter |  | Inches |  |
| :--- | ---: | ---: | ---: | ---: |
|  | Min. | Max. | Min. | Max. |
| $\mathrm{A}_{2}$ | 4.7 | 5.3 | .185 | .209 |
| $\mathrm{~A}_{1}$ | 2.2 | 2.54 | .087 | .102 |
| $\mathrm{~A}_{2}$ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| $\mathrm{~b}_{1}$ | 1.65 | 2.13 | .065 | .084 |
| $\mathrm{~b}_{2}$ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L 1 |  | 4.50 |  | .177 |
| $\varnothing \mathrm{P}$ | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

## TO-268 Outline



IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

| IXYS MOSFETs and IGBTs are covered | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065 B1 | 6,683,344 | 6,727,585 | 7,005,734 B2 | 7,157,338B2 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| by one or more of the following U.S. patents: | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343 | 6,710,405 B2 | 6,759,692 | 7,063,975 B2 |  |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505 | 6,710,463 | 6,771,478 B2 | 7,071,537 |  |

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